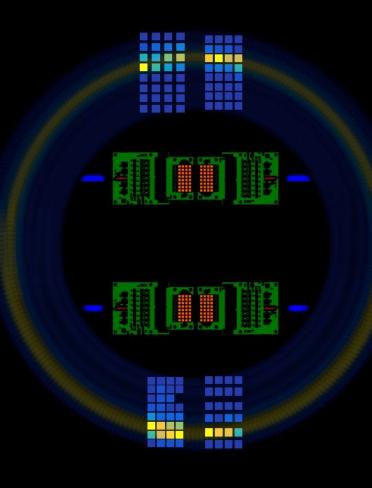
Results on SiPM with ALCOR

ALCOR for EIC meeting

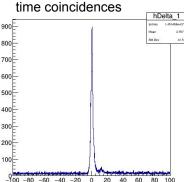


2022 test beam at CERN-PS

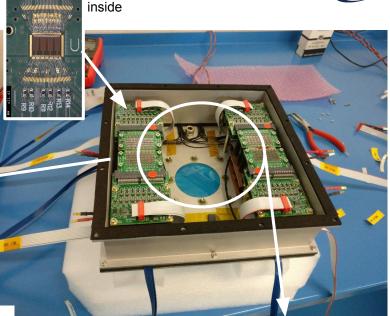
dRICH prototipe on PS beamline with SiPM-ALCOR box

beamline shared with LAPPD test

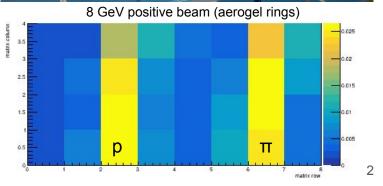
successful operation of SiPM irradiated (with protons up to 10¹⁰) and <u>annealed</u> (in oven at 150 C)



reference time (ns)



ALCOR



2022 test beam at CERN-PS

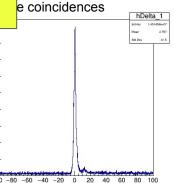
dRICH prototipe on PS beamline with SiPM-ALCOR box

but remember that we had a test-beam failure in 2021

ALCOR-v1 chip has some problems with high input rates (cf. SiPM) that prevented us to effectively take data in 2021

we managed to put in place some bricolage and tricks over one year of lab experience in Bologna and finally take bear data in 2022 beam test

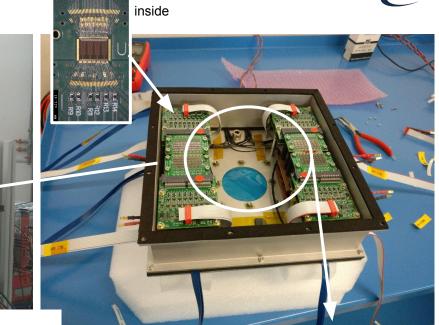
successful operation of SiPM <u>irradiated</u> (with protons up to 10¹⁰) and <u>annealed</u> (in oven at 150 C)



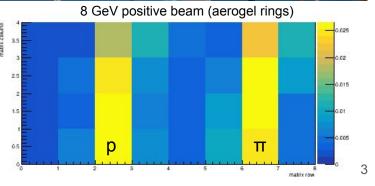
600 500

400

200F

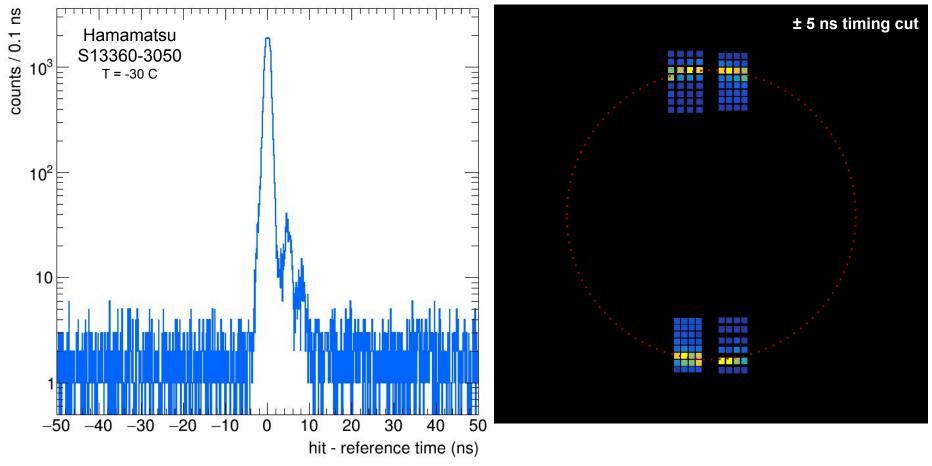


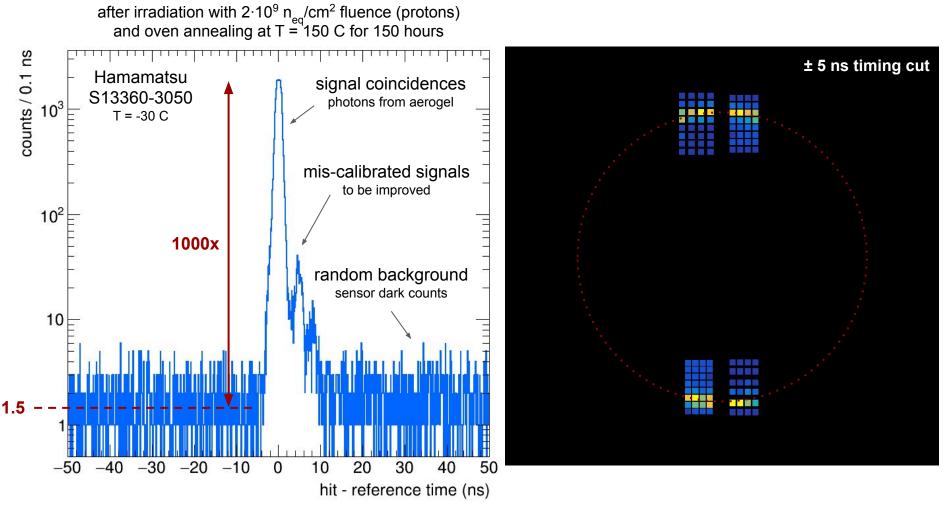
ALCOR



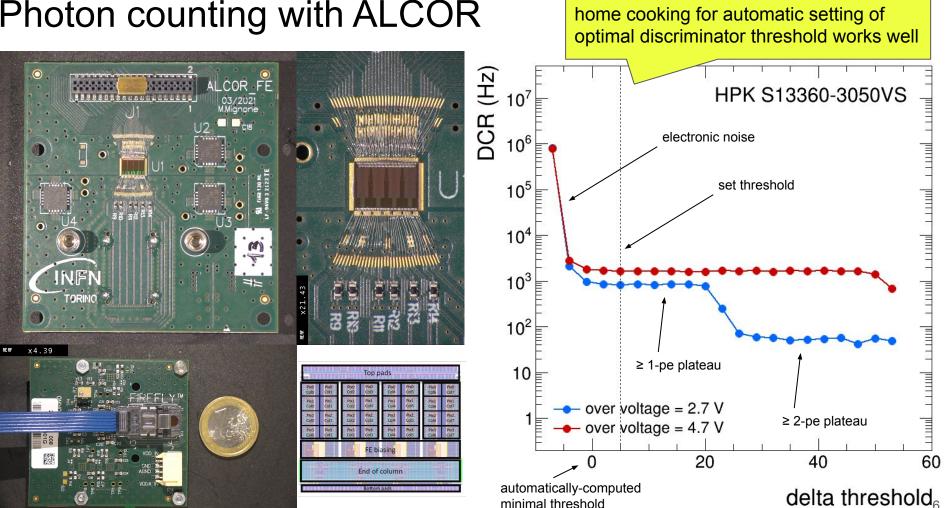


after irradiation with $2 \cdot 10^9 n_{eq}/cm^2$ fluence (protons) and oven annealing at T = 150 C for 150 hours



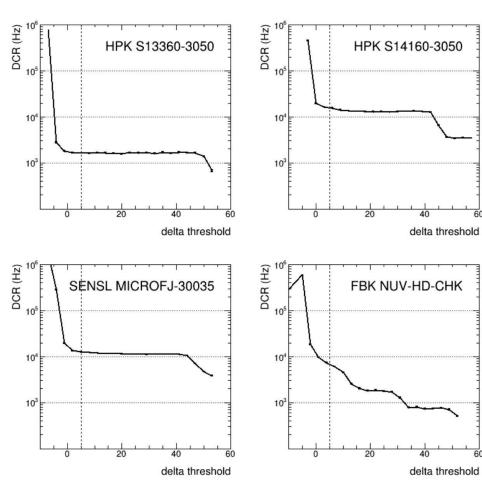


sensor DCR ~ 15 kHz



Photon counting with ALCOR

Coupling ALCOR with SiPM (FBK)



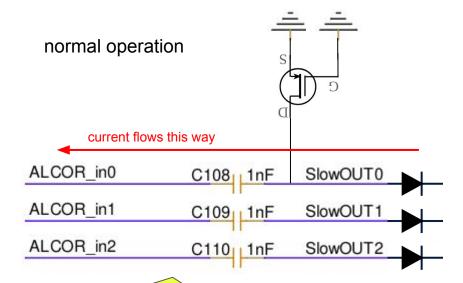
1-pe plateau for FBK sensors (large 40 um) SPAD is very short

small amplitude signals seen by ALCOR? why? in principle FBK has similar capacitance / gain as HPK sensors

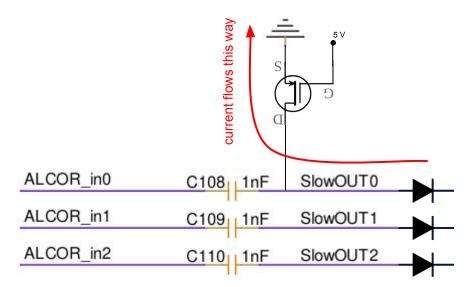
moreover the 1-pe plateau in FBK is not really a plateau

is ALCOR "more noisy" with FBK sensors? "less gainy" with FBK sensors?

need to better study how we couple ALCOR with the SiPM



we need specialised circuitry (mosfet) to be able to "disconnect" ALCOR (and other circuitry downstream the SiPM) when performing current annealing



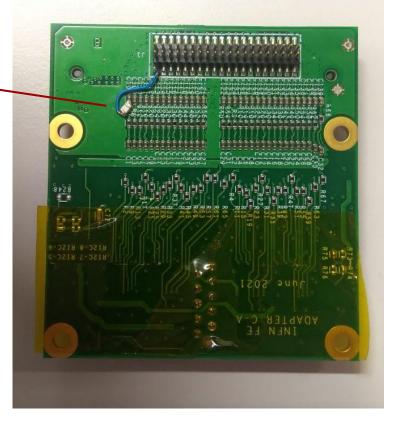
being implemented on new prototype electronics. Mosfet parasitic capacitance will "eat" part of the signal. How much? Which frequencies? Simulation? in meantime we did measurements

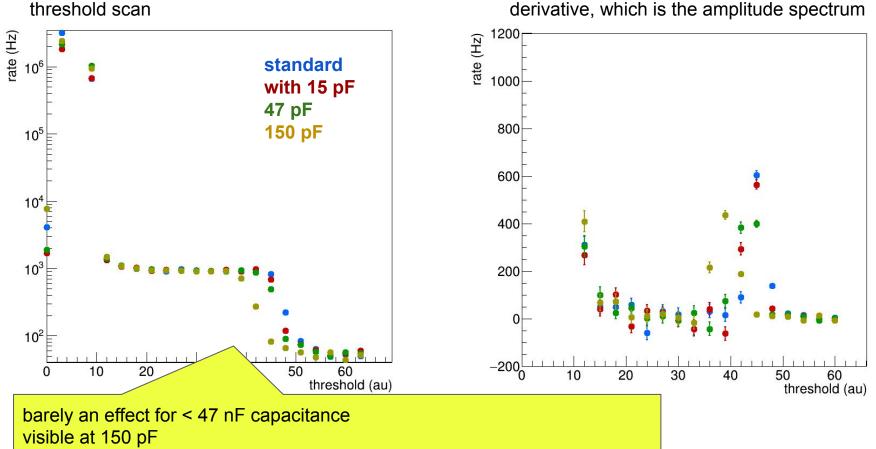
	=		
ALCOR_in0	C108 1nF	SlowOUT0	
ALCOR_in1	C109 1nF	SlowOUT1	
ALCOR_in2	C110 1nF	SlowOUT2	

very first tests using discrete capacitor used ALCOR for "the real thing" test of signal change, but how to see it?

 \rightarrow threshold scan as proxy of amplitude measurements

capacitor will "eat" high frequencies if signal decreases \rightarrow significant cut of high frequencies \rightarrow worse timing



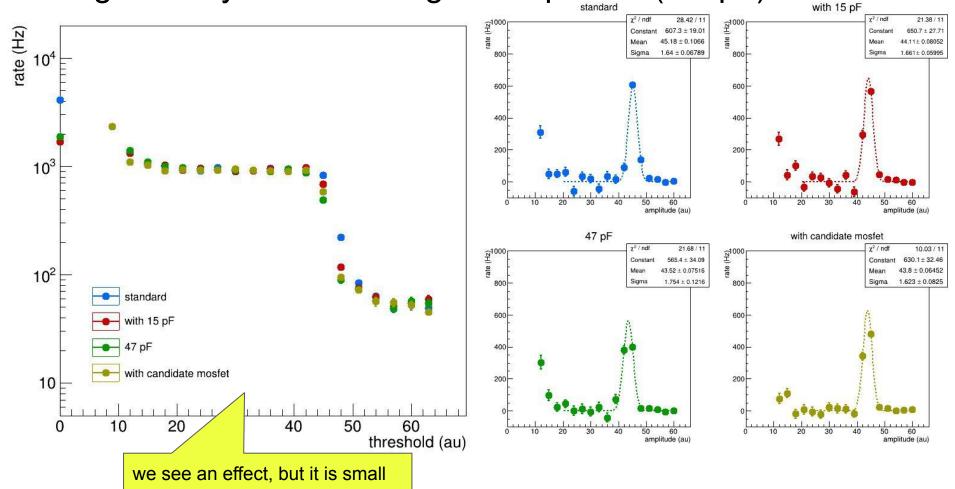


makes sense since SiPM capacitance is of similar order of magnitude

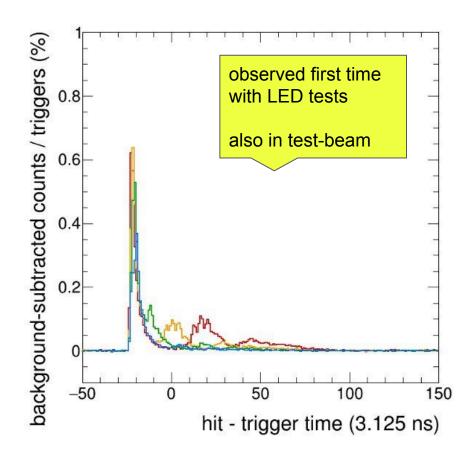
testing with the active target mosfet complus 50 ohm as a for cables for pote gate-GND DeltaV	ponent proxy	s	50 ohm
ALCOR_in0	C108	1nF	SlowOUT0
ALCOR_in1	C109	1nF	SlowOUT1
ALCOR_in2	C110	1nF	SlowOUT2

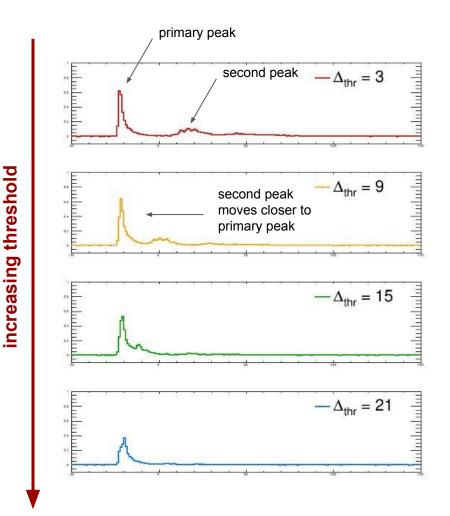


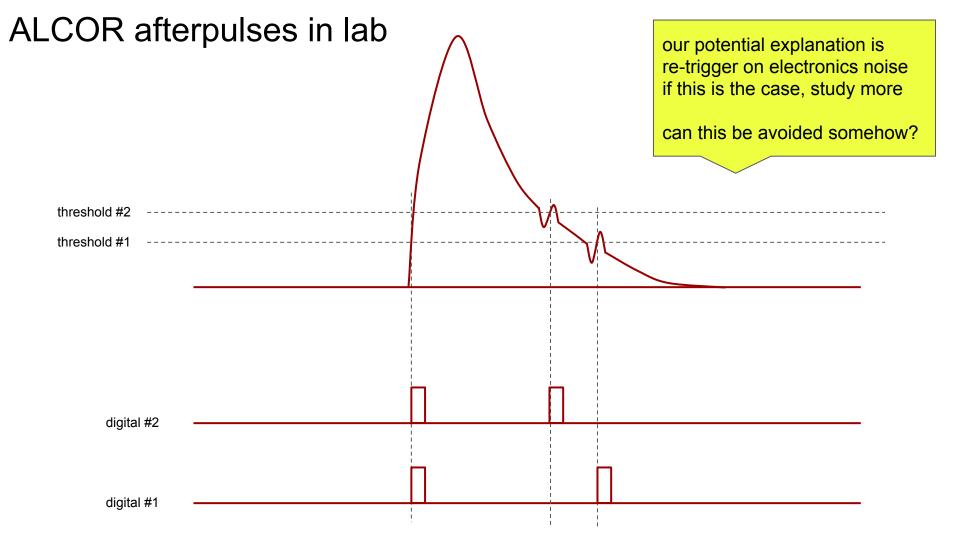




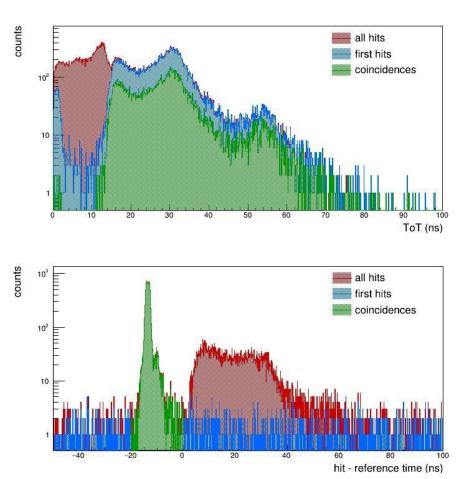
ALCOR afterpulses in lab







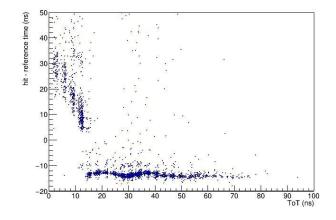
ALCOR afterpulses in test beam



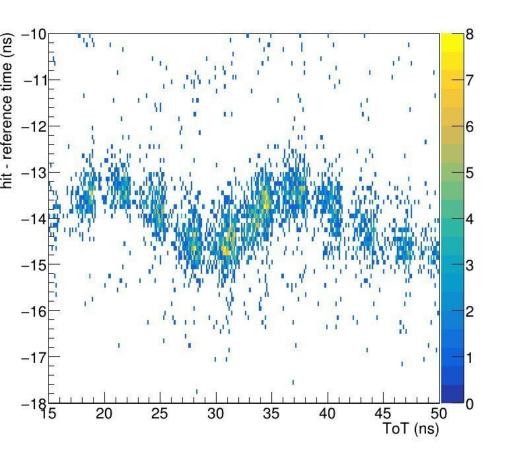
we do see afterpulses also in test beam ToT feature of ALCOR used for the first time by us in 2022 beam test

we can nicely correlate after-pulses with low ToT signals (noise ripple?0

 \rightarrow importance of having a ToT measurement to reject afterpulses (and for time resolution)



ALCOR ToT



ToT feature of ALCOR used for the first time by us in 2022 beam test

not simple to combine leading-trailing hits from TDCs, apparently not appearing in order (leading first, trailing after) in the serial data stream? several (10%) orphans?

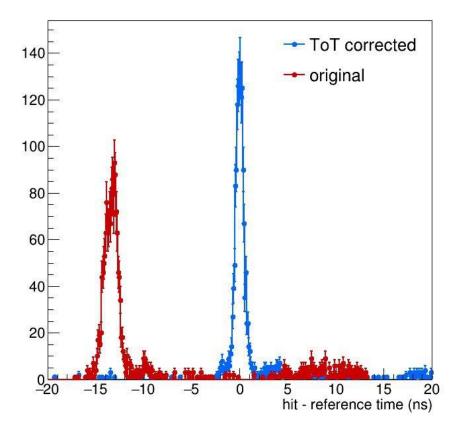
needs work to study and understand how to exploit it at best, but it is needed

very weird time-amplitude (ToT) correlation in HPK 13360 sensors

sinusoidal? fits well with 8.5 ns period... what is this? and why?

whatever it is, needs to be studied and understood

ALCOR ToT



ToT feature of ALCOR used for the first time by us in 2022 beam test

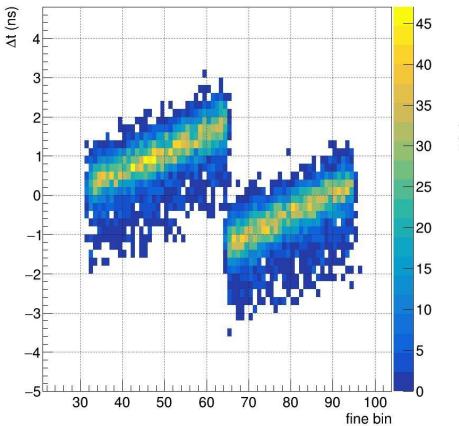
ToT is important for improving time resolution we are far from a measurement of it from the beam test, but we have a best result

which is ~ 350 ps for HPK 13360 sensors larger than what I hoped at lowish overvoltage (3 V)

is this close to the limit we can achieve with ALCOR coupled with these SiPM sensors?

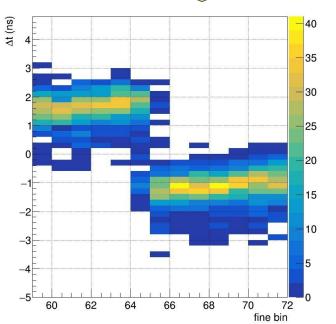
if not, we need to understand where in the electronics chain we need to improve for better timing

ALCOR fine TDC measurement



observed ambiguity in ALCOR fine TDC measurement for same TDC bin (two peak structures)

there are worse cases than this, need to look into this together and replicated in lab



Very brief summary

• we extensively used ALCOR in the last 1.5 year

- far to say that we have thoroughly tested it for EIC SiPM use
- it took time till we managed to make use of it "bypassing" the limitations (v1 bug)
- needs IMO more testing with joint efforts between users (ie. BO) and gurus (TO)

must create a strong user-guru "task force" with regular (monthly) meetings? RP planned to organise a kickstart meeting (let's meet in TO in a month?)

various observations point towards test and optimisation needs

- afterpulses (and noise that I did not show)
- proper coupling with SiPM capacitance and signal shaping
- is the measures time resolution close to what we expect we can have?
- strange features in ToT correlation, way of ToT data stream to be discussed
- TDC interpolation seems to introduce ambiguities at clock boundary

• IMO need to get our hand on v2 soon and iron out remaining wrinkles

- v1 bug prevented us to really see ALCOR working at high-rate
- we use tricks to reach MHz measurements and cope with test-beam (learnt pulse-inhibit by chance)

possible further requirements / requests

- we are AC-decoupling with discrete components, what is best to be done? do it in ALCOR?
- in electronic boards we put (expensive) DACs to fine-tune HV, put it in ALCOR (as weeroc)?
- implement "the annealing mosfet" inside ALCOR ? will it sustain current (20-30 mA/channel) ?